

MBR4040PT thru 4060PT

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 40 to 60 Volts FORWARD CURRENT - 40 Ampere

TO-247AB

FEATURES

- Metal of silicon rectifier, majority carrier conducton
- Guard ring for transient protection
- · Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequence inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

• Case: TO-3P molded plastic • Polarity: As marked on the body • Weight: 0.2 ounces, 5.6 grams • Mounting position : Any

Dim.	Min. Max.						
Α	15.45	16.25					
В	20.30	21.75					
С	20.10	19.60					
D	6.50 Typ.						
Е	3.70	4.38					
F	3.00	3.40					
G	1.80	2.20					
Н	1.00	1.40					
I	5.45 Typ.						
J	4.85	5.15					
K	1.90	2.10					
L	3.50 Typ.						
М	3.20 Typ.						
N	2.20 2.60						
0	0.51	0.76					
All Dimensions in millimeter							

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBR 4040PT	MBR 4045PT	MBR 4060PT	UNIT
Maximum Recunent Peak Reverse Voltage	V _{RRM}	40	45	60	V
Maximum RMS Voltage	V _{RMS}	28	31.5	42	V
Maximum DC Blocking Voltage	V _{DC}	40	45	60	V
Maximum Average Forward Rectified Current (See Fig.1) @Tc=125°C	I _(AV)	40			А
Peak Forward Surge current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	I _{PSM}	400			А
Voltage Rate of Change (Rated VR)	dv/dt	10000			V/us
I=20A @T=25°C Maximum forward I=20A @T=125°C Voltage (Note 1) I=40A @T=25°C I=40A @T=125°C	V _F	0.70 0.80 0.60 0.70 0.80 - 0.75 -		0.70	v
Maximum DC Reverse Current @T=25°C at Rated DC Blocking Voltage @T=125°C	I_R	1.0 100			mA
Typical Thermal Resistance (Note 2)	Resc	1.4			°C/W
Typical Junction Capacitance per element (Note 3)	C _J	700			pF
Operating Temperature Range	TJ	-55 to +150			t
Storage Temperature Range	T _{STG}	-55 to +175			t
NOTES: 1. 300us Pulse Width, 2% Duty Cycle. REV.0, 01Oct-2013					

- 2. Thermal Resistance Junction to Case.
- 3. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

